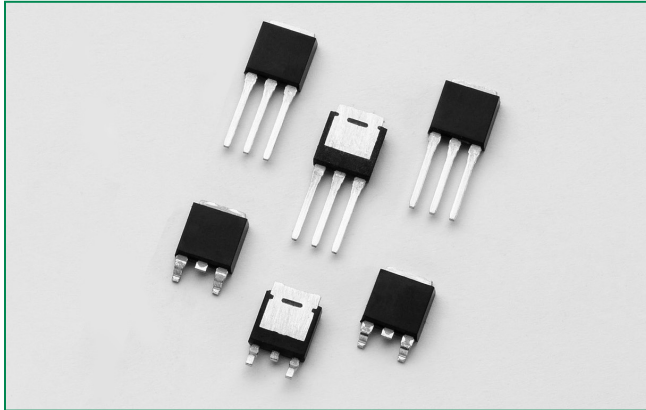




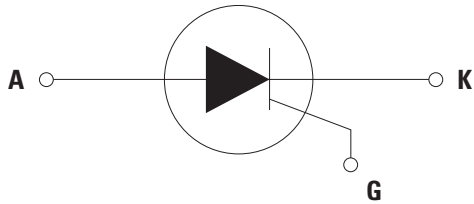
SJxx06xSx & SJxx06xx Series



Main Features

Symbol	Value	Unit
$I_{T(RMS)}$	6	A
V_{DRM}/V_{RRM}	400 or 600	V
I_{GT}	0.2 to 15	mA

Schematic Symbol



Description

This SJxx06xx high temperature SCR series is ideal for uni-directional switch applications such as phase control, heating, motor speed controls, converters/rectifiers and capacitive discharge ignitions.

These SCRs have a low gate current trigger level of 6mA or 15mA maximum at approximately 1.5V, with a sensitive version of this series having a gate trigger current less than 200µA.

Features & Benefits

- Voltage capability up to 600V
- Surge capability up to 100A at 60Hz half cycle
- 150°C maximum junction temperature
- Halogen free and RoHS compliant

Applications

Typical applications includes capacitive discharge system for motorcycle engine CDI, portable generator engine ignition, strobe lights and nailers, as well as generic rectifiers, battery voltage regulators and converters. Also controls for power tools, home/brown goods and white goods appliances.



Absolute Maximum Ratings — Sensitive SCRs

Symbol	Parameter	Test Conditions	Value	Unit
$I_{T(RMS)}$	RMS on-state current	$T_c = 120^\circ\text{C}$	6	A
$I_{T(AV)}$	Average on-state current	$T_c = 120^\circ\text{C}$	3.84	A
I_{TSM}	Peak non-repetitive surge current	single half cycle; $f = 50\text{ Hz}$; $T_J(\text{initial}) = 25^\circ\text{C}$	83	A
		single half cycle; $f = 60\text{ Hz}$; $T_J(\text{initial}) = 25^\circ\text{C}$	100	
I^2t	I^2t Value for fusing	$t_p = 8.3\text{ms}$	41	A^2s
di/dt	Critical rate of rise of on-state current	$f = 60\text{ Hz}$, $T_J = 150^\circ\text{C}$	70	$\text{A}/\mu\text{s}$
I_{GM}	Peak gate current	$P_W = 20\text{ }\mu\text{s}$, $T_J = 150^\circ\text{C}$	0.5	A
$P_{G(AV)}$	Average gate power dissipation	$T_J = 150^\circ\text{C}$	0.1	W
T_{stg}	Storage temperature range		-40 to 150	$^\circ\text{C}$
T_J	Operating junction temperature range		-40 to 150	$^\circ\text{C}$
V_{DSM}/V_{RSM}	Peak non-repetitive blocking voltage	$P_W = 100\text{ }\mu\text{s}$	$V_{DRM}/V_{RRM} + 100$	V

Absolute Maximum Ratings — Standard SCRs

Symbol	Parameter	Test Conditions	Value	Unit
$I_{T(RMS)}$	RMS on-state current	$T_c = 125^\circ\text{C}$	6	A
$I_{T(AV)}$	Average on-state current	$T_c = 125^\circ\text{C}$	3.84	A
I_{TSM}	Peak non-repetitive surge current	single half cycle; $f = 50\text{ Hz}$; $T_J(\text{initial}) = 25^\circ\text{C}$	83	A
		single half cycle; $f = 60\text{ Hz}$; $T_J(\text{initial}) = 25^\circ\text{C}$	100	
I^2t	I^2t Value for fusing	$t_p = 8.3\text{ ms}$	41	A^2s
di/dt	Critical rate-of-rise of on-state current	$f = 60\text{ Hz}$, $T_J = 150^\circ\text{C}$	100	$\text{A}/\mu\text{s}$
I_{GM}	Peak gate current	$P_W = 20\text{ }\mu\text{s}$, $T_J = 150^\circ\text{C}$	4	A
$P_{G(AV)}$	Average gate power dissipation	$T_J = 150^\circ\text{C}$	1	W
P_{GM}	Peak gate power dissipation	$t_p = 20\text{ }\mu\text{s}$, $T_J = 150^\circ\text{C}$	10	W
T_{stg}	Storage temperature range		-40 to 150	$^\circ\text{C}$
T_J	Operating junction temperature range		-40 to 150	$^\circ\text{C}$
V_{DSM}/V_{RSM}	Peak non-repetitive blocking voltage	$P_W = 100\text{ }\mu\text{s}$	$V_{DRM}/V_{RRM} + 100$	V

Electrical Characteristics ($T_J = 25^\circ\text{C}$, unless otherwise specified) — Sensitive SCRs

Symbol	Test Conditions		Value	Unit
			SJxx06xS2	
I_{GT}	$V_D = 6\text{ V}$, $R_L = 100\text{ }\Omega$	MIN.	20	μA
V_{GT}		MAX.	200	μA
dv/dt		MAX.	0.8	V
V_{GD}	$V_D = V_{DRM}$; $R_{GK} = 220\text{ }\Omega$; $T_J = 125^\circ\text{C}$	MIN.	15	$\text{V}/\mu\text{s}$
	$V_D = V_{DRM}$; $R_L = 3.3\text{ k}\Omega$; $T_J = 125^\circ\text{C}$	MIN.	0.2	V
	$V_D = V_{DRM}$; $R_L = 3.3\text{ k}\Omega$; $T_J = 150^\circ\text{C}$	MIN.	0.1	V
V_{GRM}	$I_{GR} = 10\text{ }\mu\text{A}$	MIN.	6	V
I_H	$I_T = 20\text{ mA}$ (initial)	MAX.	6	mA
t_q	$t_p = 50\text{ }\mu\text{s}$; $dv/dt = 5\text{ V}/\mu\text{s}$; $di/dt = -30\text{ A}/\mu\text{s}$	MAX.	130	μs
t_{gt}	$I_G = 2 \times I_{GT}$; $P_W = 15\text{ }\mu\text{s}$; $I_T = 8\text{ A}$	TYP.	6	μs

NOTE: xx = voltage



Electrical Characteristics ($T_J = 25^\circ\text{C}$, unless otherwise specified) – Standard SCRs

Symbol	Test Conditions		Value		Unit
			SJxx06x1	SJxx06x	
I_{GT}	$V_D = 12\text{ V}$ $R_L = 60\ \Omega$	MAX.	6	15	mA
V_{GT}		MAX.	1.5	1.5	V
dv/dt	$V_D = V_{DRM}$; gate open; $T_J = 125^\circ\text{C}$	MIN.	100	200	V/ μs
	$V_D = V_{DRM}$; gate open; $T_J = 150^\circ\text{C}$		50	120	
V_{GD}	$V_D = V_{DRM}$; $R_L = 3.3\text{ k}\Omega$; $T_J = 125^\circ\text{C}$	MIN.	0.2	0.2	V
	$V_D = V_{DRM}$; $R_L = 3.3\text{ k}\Omega$; $T_J = 150^\circ\text{C}$	MIN.	0.1	0.1	
V_{GRM}	$I_{GR} = 10\ \mu\text{A}$	MIN.	6	6	V
I_H	$I_T = 200\text{ mA}$ (initial)	MAX.	20	30	mA
t_q	$I_T = 0.5\text{ A}$; $t_p = 50\ \mu\text{s}$; $dv/dt = 5\text{ V}/\mu\text{s}$; $di/dt = 30\text{ A}/\mu\text{s}$	MAX.	30	35	μs
t_{gt}	$I_G = 2 \times I_{GT}$; $P_W = 15\ \mu\text{s}$; $I_T = 8\text{ A}$	TYP.	0.5	2	μs

NOTE: xx = voltage

Static Characteristics

Symbol	Test Conditions				Value	Unit
V_{TM}	$I_T = 12\text{ A}$; $t_p = 380\ \mu\text{s}$				MAX.	1.6 V
I_{DRM} / I_{RRM}	@ V_{DRM} / V_{RRM}	SJxx06xS2	$T_J = 25^\circ\text{C}$	400 - 600 V	MAX.	5
			$T_J = 125^\circ\text{C}$, $R_{GK} = 220\ \Omega$	400 - 600 V		1000
			$T_J = 150^\circ\text{C}$, $R_{GK} = 220\ \Omega$	400 - 600 V		3000
		SJxx06xx	$T_J = 25^\circ\text{C}$	400 - 600 V		10
			$T_J = 125^\circ\text{C}$	400 - 600 V		1000
			$T_J = 150^\circ\text{C}$	400 - 600 V		3000

Thermal Resistances

Symbol	Parameter		Value	Unit
$R_{\theta(JC)}$	Junction to case (AC)	SJxx06xS2	1.2	$^\circ\text{C}/\text{W}$
		SJxx06xx	1.2	

Note: xx = voltage

Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature (Sensitive SCR)

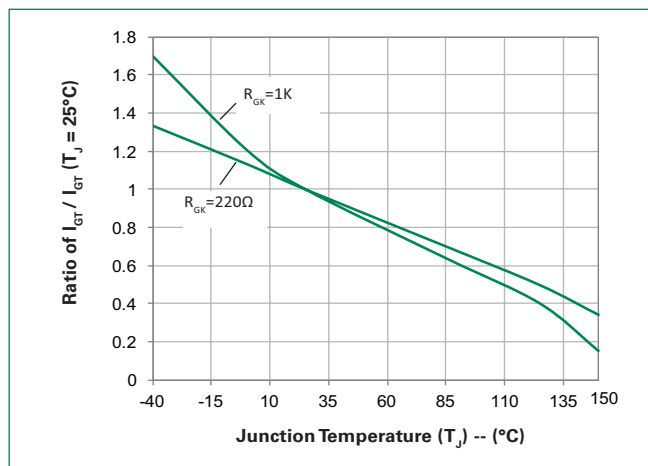


Figure 2: Normalized DC Gate Trigger Current vs. Junction Temperature (Standard SCR)

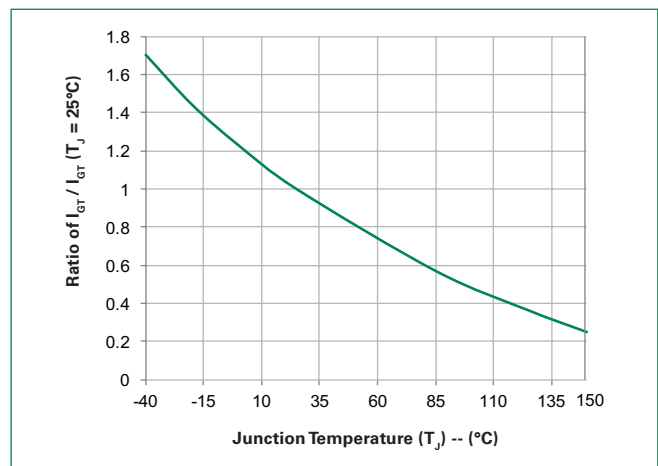




Figure 3: Normalized DC Gate Trigger Voltage vs. Junction Temperature

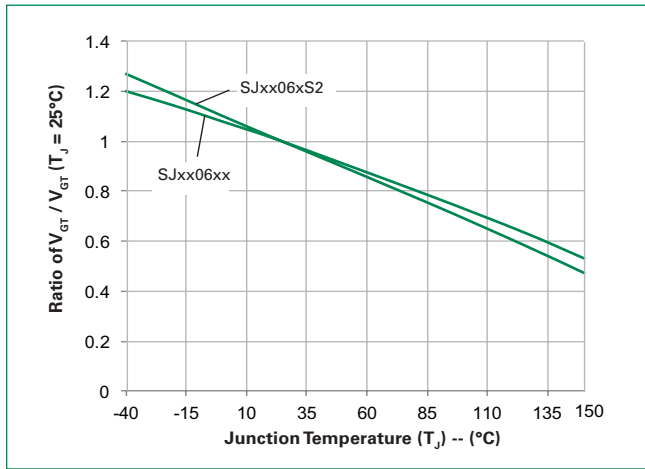


Figure 4: Normalized DC Holding Current vs. Junction Temperature

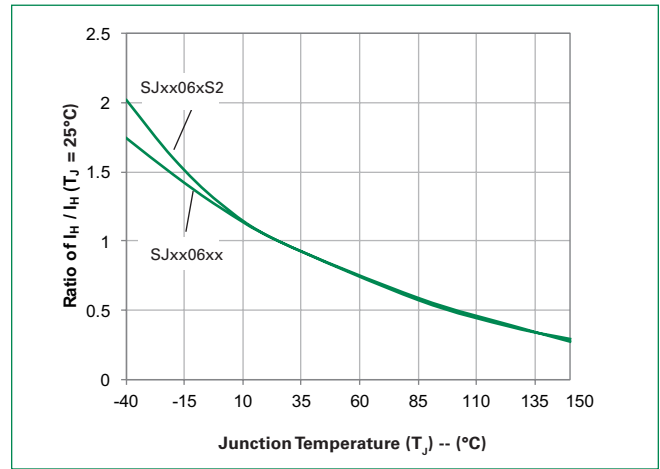


Figure 5: On-State Current vs. On-State Voltage (Typical)

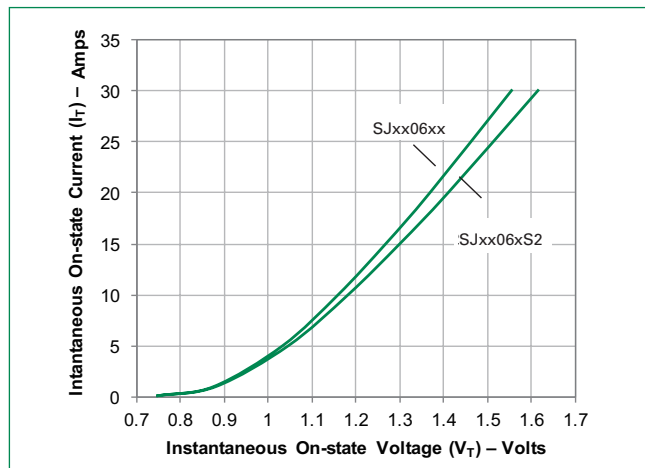


Figure 6: Power Dissipation (Typical) vs. RMS On-State Current

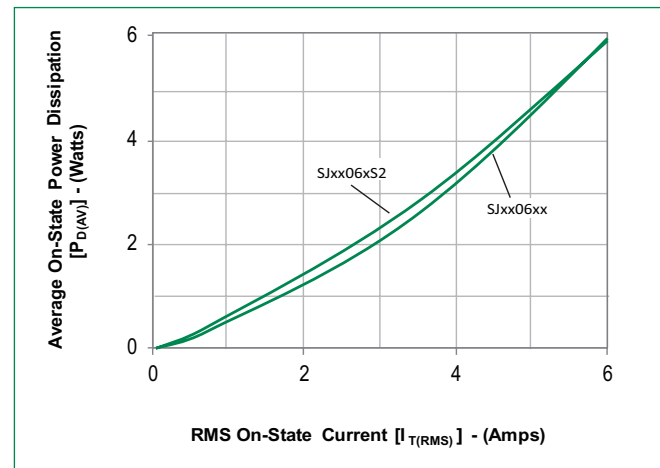


Figure 7: Maximum Allowable Case Temperature vs. RMS On-State Current

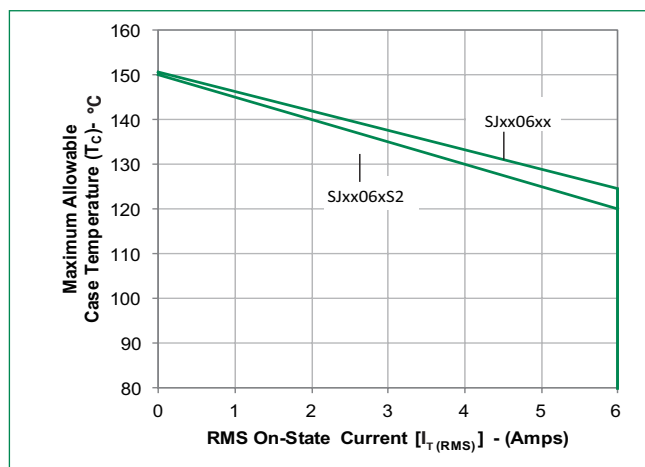


Figure 8: Maximum Allowable Case Temperature vs. Average On-State Current

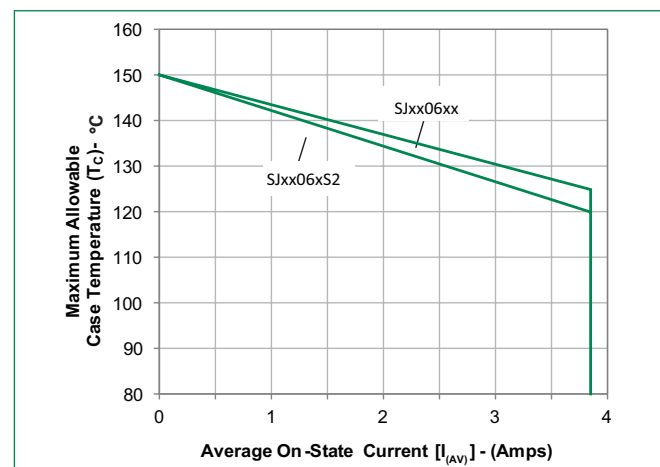




Figure 9: Peak Capacitor Discharge Current

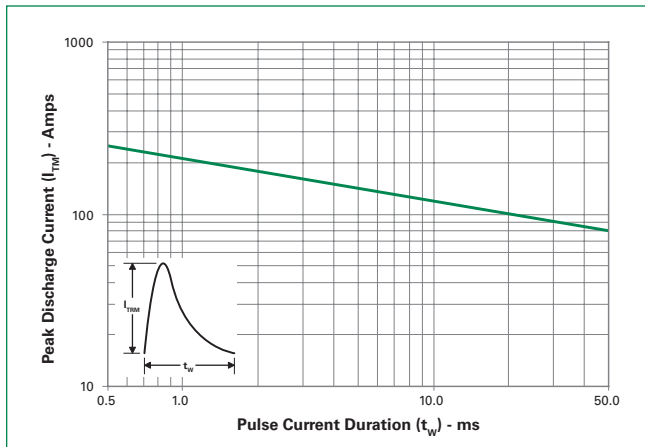


Figure 10: Surge Peak On-State Current vs. Number of Cycles

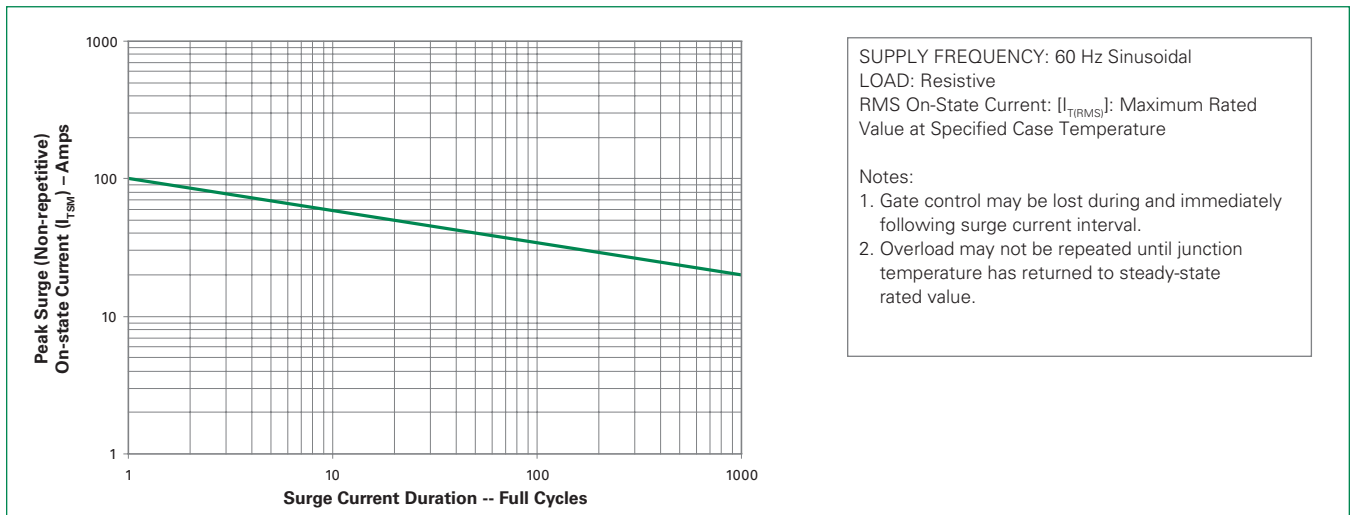


Figure 11: Typical DC Gate Trigger Current with R_{GK} vs. Junction Temperature (Sensitive SCR)

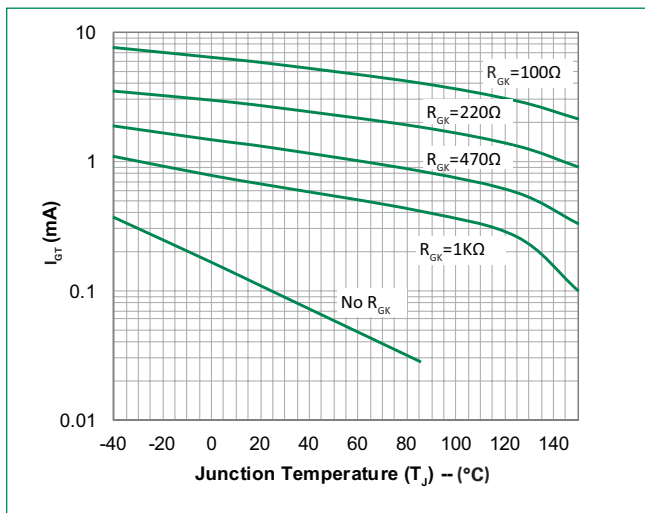


Figure 12: Typical DC Holding Current with R_{GK} vs. Junction Temperature (Sensitive SCR)

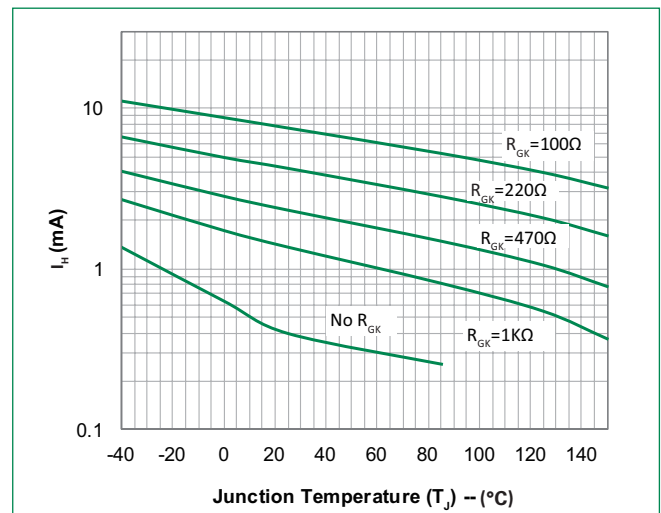
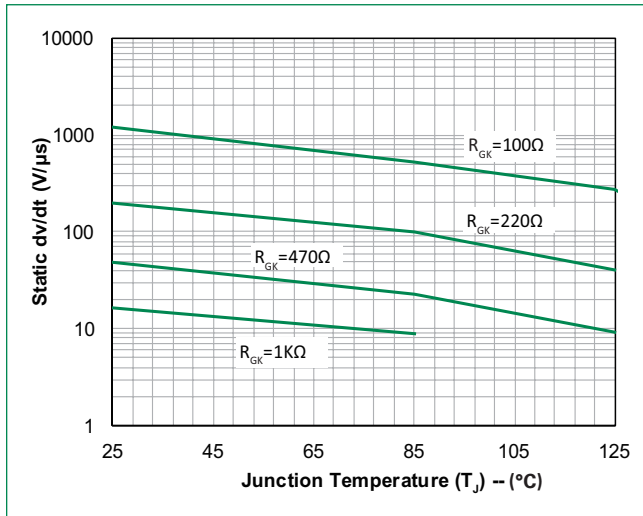


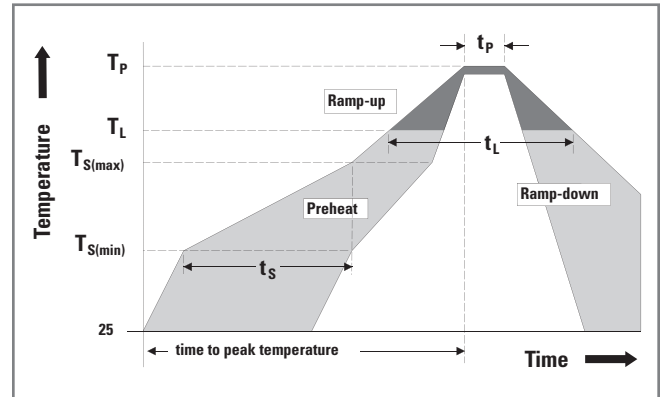


Figure 13: Typical Static dv/dt with R_{GK} vs. Junction Temperature (Sensitive SCR)



Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp) (T_L) to peak		5°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		5°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Time (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		280°C



Physical Specifications

Terminal Finish	100% Matte Tin-plated
Body Material	UL Recognized compound meeting flammability rating V-0
Lead Material	Copper Alloy

Design Considerations

Careful selection of the correct component for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the component rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Environmental Specifications

Test	Specifications and Conditions
AC Blocking	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage for 1008 hours
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time
Temperature/Humidity	EIA / JEDEC, JESD22-A101 1008 hours; 160V - DC: 85°C; 85% rel humidity
High Temp Storage	MIL-STD-750, M-1031, 1008 hours; 150°C
Low-Temp Storage	1008 hours; -40°C
Resistance to Solder Heat	MIL-STD-750 Method 2031
Solderability	ANSI/J-STD-002, category 3, Test A
Lead Bend	MIL-STD-750, M-2036 Cond E
Moisture Sensitivity Level	Level 1, JEDEC-J-STD-020

Product Selector

Part Number	Voltage		Gate Sensitivity	Type	Package
	400V	600V			
SJxx06VS2	X	X	0.2mA	Sensitive SCR	TO-251
SJxx06DS2	X	X	0.2mA	Sensitive SCR	TO-252
SJxx06V	X	X	15mA	Standard SCR	TO-251
SJxx06D	X	X	15mA	Standard SCR	TO-252
SJxx06V1	X	X	6mA	Standard SCR	TO-251
SJxx06D1	X	X	6mA	Standard SCR	TO-252

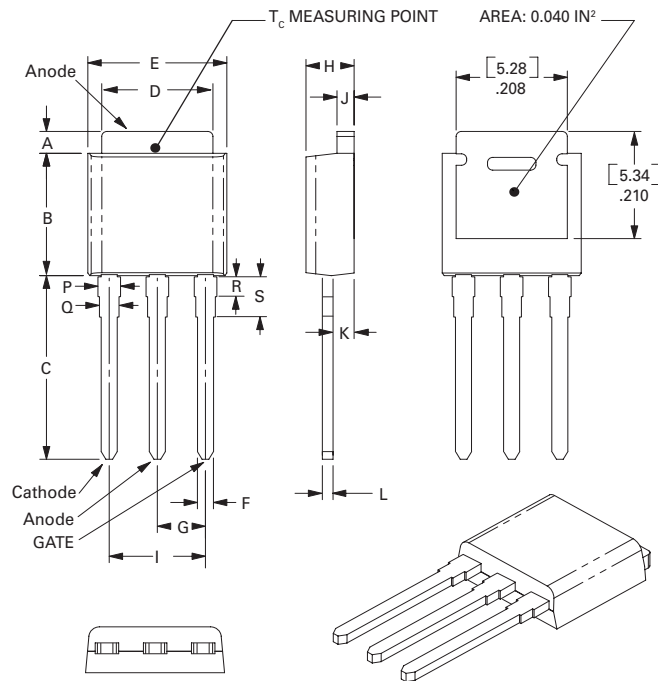
Note: xx = Voltage

Packing Options

Part Number	Marking	Weight	Packing Mode	Base Quantity
SJxx06DS2TP	SJxx06DS2	0.3 g	Tube	750 (75 per tube)
SJxx06DS2RP	SJxx06DS2	0.3 g	Embossed Carrier	2500
SJxx06VS2TP	SJxx06VS2	0.4 g	Tube	750 (75 per tube)
SJxx06DTP	SJxx06D	0.3 g	Tube	750 (75 per tube)
SJxx06DRP	SJxx06D	0.3 g	Embossed Carrier	2500
SJxx06VTP	SJxx06V	0.4 g	Tube	750 (75 per tube)
SJxx06D1TP	SJxx06D1	0.3 g	Tube	750 (75 per tube)
SJxx06D1RP	SJxx06D1	0.3 g	Embossed Carrier	2500
SJxx06V1TP	SJxx06V1	0.4 g	Tube	750 (75 per tube)

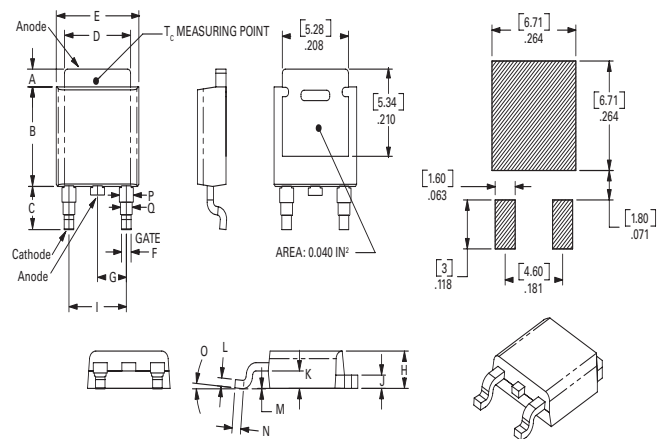
Note: xx = Voltage

Dimensions — TO-251AA (V/I-Package) — V/I-PAK Through Hole



Dimension	Inches			Millimeters		
	Min	Typ	Max	Min	Typ	Max
A	0.037	0.040	0.043	0.94	1.01	1.09
B	0.235	0.242	0.245	5.97	6.15	6.22
C	0.350	0.361	0.375	8.89	9.18	9.53
D	0.205	0.208	0.213	5.21	5.29	5.41
E	0.255	0.262	0.265	6.48	6.66	6.73
F	0.027	0.031	0.033	0.69	0.80	0.84
G	0.087	0.090	0.093	2.21	2.28	2.36
H	0.085	0.092	0.095	2.16	2.34	2.41
I	0.176	0.180	0.184	4.47	4.57	4.67
J	0.018	0.020	0.023	0.46	0.51	0.58
K	0.035	0.037	0.039	0.90	0.95	1.00
L	0.018	0.020	0.023	0.46	0.52	0.58
P	0.042	0.047	0.052	1.06	1.20	1.32
Q	0.034	0.039	0.044	0.86	1.00	1.11
R	0.034	0.039	0.044	0.86	1.00	1.11
S	0.074	0.079	0.084	1.86	2.00	2.11

Dimensions — TO-252AA (D-Package) — D-PAK Surface Mount

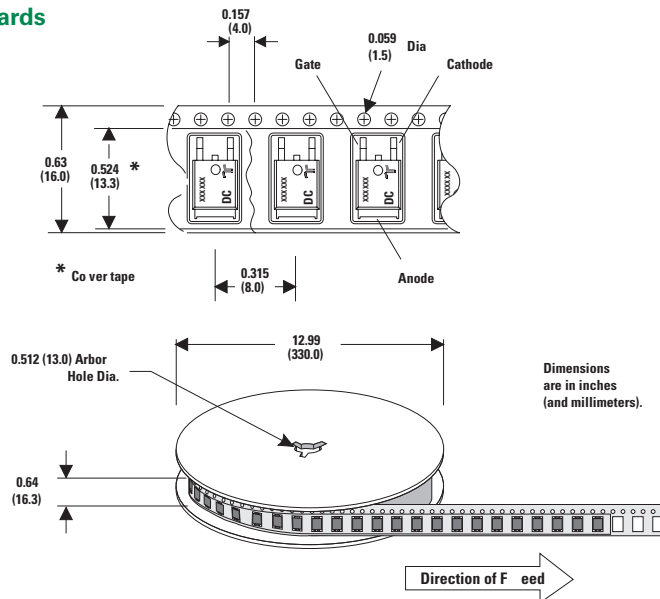


Dimension	Inches			Millimeters		
	Min	Typ	Max	Min	Typ	Max
A	0.037	0.040	0.043	0.94	1.01	1.09
B	0.235	0.243	0.245	5.97	6.16	6.22
C	0.106	0.108	0.113	2.69	2.74	2.87
D	0.205	0.208	0.213	5.21	5.29	5.41
E	0.255	0.262	0.265	6.48	6.65	6.73
F	0.027	0.031	0.033	0.69	0.80	0.84
G	0.087	0.090	0.093	2.21	2.28	2.36
H	0.085	0.092	0.095	2.16	2.33	2.41
I	0.176	0.179	0.184	4.47	4.55	4.67
J	0.018	0.020	0.023	0.46	0.51	0.58
K	0.035	0.037	0.039	0.90	0.95	1.00
L	0.018	0.020	0.023	0.46	0.51	0.58
M	0.000	0.000	0.004	0.00	0.00	0.10
N	0.021	0.026	0.027	0.53	0.67	0.69
O	0°	0°	5°	0°	0°	5°
P	0.042	0.047	0.052	1.06	1.20	1.32
Q	0.034	0.039	0.044	0.86	1.00	1.11

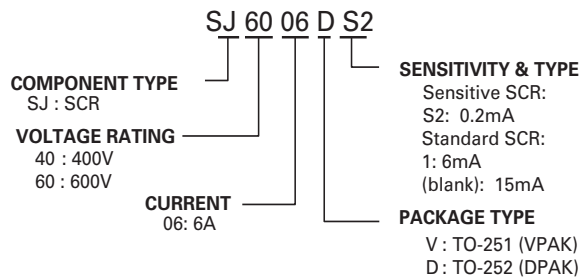


TO-252 Embossed Carrier Reel Pack (RP) Specifications

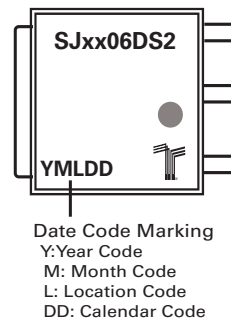
Meets all EIA-481-2 Standards



Part Numbering System



Part Marking System



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